

1A, 30V - 60V Schottky Barrier Surface Mount Rectifier

FEATURES

- Very low profile typical height of 0.68mm
- Low power loss, high efficiency
- Ideal for automated placement
- Moisture sensitivity level: level 1, per J-STD-020
- RoHS Compliant
- Halogen-free according to IEC 61249-2-21

APPLICATIONS

- Switching mode power supply (SMPS)
- Adapters
- DC to DC converter

MECHANICAL DATA

- Case: Micro SMA
- Molding compound meets UL 94V-0 flammability rating
- Terminal: Matte tin plated leads, solderable per J-STD-002
- Meet JESD 201 class 2 whisker test
- Polarity: Indicated by cathode band
- Weight: 0.006g (approximately)

KEY PARAMETERS			
PARAMETER	VALUE	UNIT	
I _F	1	Α	
V_{RRM}	30 - 60	V	
I _{FSM}	25	Α	
T _{J MAX}	150	°C	
Package	Micro SMA		
Configuration	Single die		









Micro SMA



ABSOLUTE MAXIMUM RATINGS (T _A = 25°C unless otherwise noted)					
PARAMETER	SYMBOL	SS13M	SS14M	SS16M	UNIT
Marking code on the device		Α	В	С	
Repetitive peak reverse voltage	V_{RRM}	30	40	60	V
Reverse voltage, total rms value	$V_{R(RMS)}$	21	28	42	V
Forward current	I _F	1		Α	
Surge peak forward current, 8.3ms single half sine wave superimposed on rated load	I _{FSM}	25		А	
Junction temperature	TJ	-55 to +150		°C	
Storage temperature	T _{STG}	-55 to +150		°C	



THERMAL PERFORMANCE			
PARAMETER	SYMBOL	TYP	UNIT
Junction-to-lead thermal resistance	$R_{\Theta JL}$	30	°C/W
Junction-to-ambient thermal resistance	$R_{\Theta JA}$	125	°C/W
Junction-to-case thermal resistance	R _{eJC}	40	°C/W

ELECTRICAL SPECIFICATIONS (T _A = 25°C unless otherwise noted)						
PARAMETER		CONDITIONS	SYMBOL	TYP	MAX	UNIT
		$I_F = 0.5A, T_J = 25^{\circ}C$	V _F	0.45	-	V
	SS13M	$I_F = 1.0A, T_J = 25$ °C		0.52	0.55	V
	SS14M	$I_F = 0.5A, T_J = 125$ °C		0.35	-	V
		$I_F = 1.0A, T_J = 125$ °C		0.46	0.50	V
Forward voltage ⁽¹⁾		$I_F = 0.5A, T_J = 25^{\circ}C$	V _F	0.51	-	V
	004614	$I_F = 1.0A, T_J = 25$ °C		0.64	0.68	V
	SS16M	$I_F = 0.5A, T_J = 125$ °C		0.46	-	V
		$I_F = 1.0A, T_J = 125$ °C		0.57	0.60	V
Reverse current @ rated V _R ⁽²⁾		T _J = 25°C	I _R	-	50	μA
		T _J = 125°C		-	10	mA
Junction capacitance	SS13M	1MHz, V _R = 4.0V	CJ	50	-	pF
	SS14M SS16M			40	-	pF

Notes:

- 1. Pulse test with PW = 0.3ms
- 2. Pulse test with PW = 30ms

ORDERING INFORMATION			
ORDERING CODE ⁽¹⁾	PACKAGE	PACKING	
SS1xM	Micro SMA	12,000 / Tape & Reel	

Notes:

1. "x" defines voltage from 30V(SS13M) to 60V(SS16M)



CHARACTERISTICS CURVES

 $(T_A = 25^{\circ}C \text{ unless otherwise noted})$

Fig.1 Forward Current Derating Curve

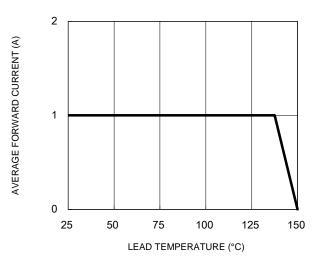


Fig.3 Typical Reverse Characteristics

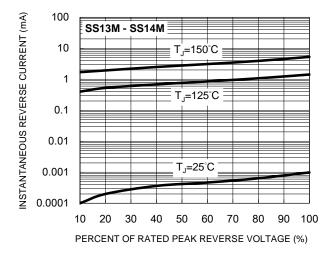


Fig.5 Typical Reverse Characteristics

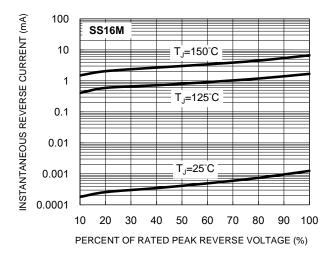


Fig.2 Typical Junction Capacitance

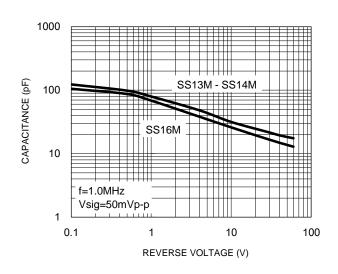


Fig.4 Typical Forward Characteristics

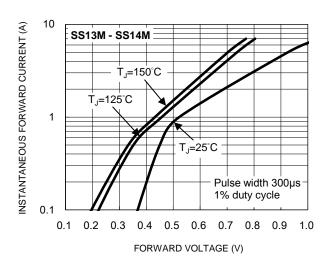
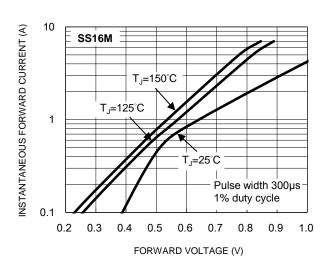


Fig.6 Typical Forward Characteristics





CHARACTERISTICS CURVES

 $(T_A = 25^{\circ}C \text{ unless otherwise noted})$

Fig.7 Maximum Non-Repetitive Forward Surge Current

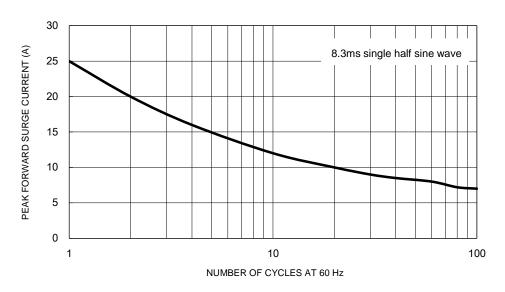
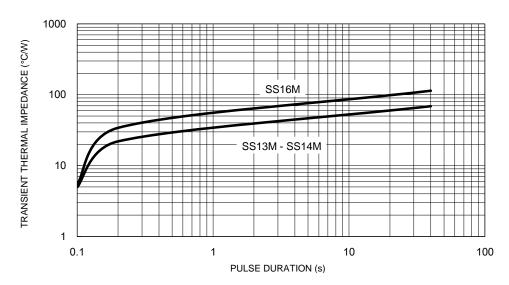


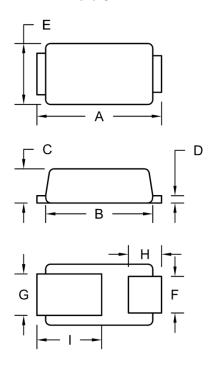
Fig.8 Typical Transient Thermal Impedance





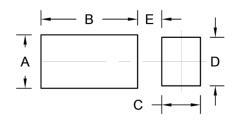
PACKAGE OUTLINE DIMENSIONS

Micro SMA



DIM.	Unit (mm)		Unit (nit (inch)	
Dilvi.	Min.	Max.	Min.	Max.	
Α	2.30	2.70	0.091	0.106	
В	2.10	2.30	0.083	0.091	
С	0.63	0.73	0.025	0.029	
D	0.10	0.20	0.004	0.008	
E	1.15	1.35	0.045	0.053	
F	0.65	0.85	0.026	0.034	
G	0.75	0.95	0.030	0.037	
Н	0.55	0.75	0.022	0.030	
I	1.10	1.50	0.043	0.059	

SUGGESTED PAD LAYOUT



Symbol	Unit (mm)	Unit (inch)
Α	1.10	0.043
В	2.00	0.079
С	0.80	0.031
D	1.00	0.039
E	0.50	0.020

MARKING DIAGRAM



P/N = Marking Code ΥW = Data Code



Taiwan Semiconductor

Notice

Specifications of the products displayed herein are subject to change without notice. TSC or anyone on its behalf assumes no responsibility or liability for any errors or inaccuracies.

Purchasers are solely responsible for the choice, selection, and use of TSC products and TSC assumes no liability for application assistance or the design of Purchasers' products.

Information contained herein is intended to provide a product description only. No license, express or implied, to any intellectual property rights is granted by this document. Except as provided in TSC's terms and conditions of sale for such products, TSC assumes no liability whatsoever, and disclaims any express or implied warranty, relating to sale and/or use of TSC products including liability or warranties relating to fitness for a particular purpose, merchantability, or infringement of any patent, copyright, or other intellectual property right.

The products shown herein are not designed for use in medical, life-saving, or life-sustaining applications. Customers using or selling these products for use in such applications do so at their own risk and agree to fully indemnify TSC for any damages resulting from such improper use or sale.

X-ON Electronics

Largest Supplier of Electrical and Electronic Components

Click to view similar products for Schottky Diodes & Rectifiers category:

Click to view products by Taiwan Semiconductor manufacturer:

Other Similar products are found below:

MA4E2039 MMBD301M3T5G RB160M-50TR D83C BAS16E6433HTMA1 BAS 3010S-02LRH E6327 BAT 54-02LRH E6327

NRVBAF360T3G NSR05F40QNXT5G NTE555 JANS1N6640 SS3003CH-TL-E GA01SHT18 CRS10I30A(TE85L,QM MBRA140TRPBF

MBRB30H30CT-1G BAT 15-04R E6152 JANTX1N5712-1 DMJ3940-000 SB007-03C-TB-E NRVBB20100CTT4G NRVBM120LT1G

NTSB30U100CT-1G CRG04(T5L,TEMQ) ACDBA1100LR-HF ACDBA1200-HF ACDBA240-HF ACDBA3100-HF CDBQC0530L-HF

ACDBA260LR-HF ACDBA1100-HF 10BQ015-M3/5BT NRVBM120ET1G VSSB410S-M3/5BT 1N5819T-G PDS1040Q-13 B160BQ-13-F

SDM05U20CSP-7 BAS 70-07 E6433 B140S1F-7 HSM560Je3/TR13 DDB2265-000 ZHCS506QTA HSM190Je3/TR13 B330AF-13

ACDBUC0230-HF SDM1U100S1F-7 MBR10200CTF-G1 CDLL5712 DMF2822-000